NSN 5961-01-080-1889



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-080-1889 **Inclosure Material:** Metal **Overall Length:** 1.553 inches **Overall Height:** 0.380 inches **Overall Width:** 1.050 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 collector to base voltage/static/emitter open and 90.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 5.00 amperes source cutoff current and 20.00 amperes source cutoff current **Power Rating Per Characteristic:** 140.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 06509-122024 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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